

# ATLAS ITk Pixel quad module test beam measurements

10th Beam Telescope and Test Beam Workshop  
20–24 June 2022  
Lecce (Italy)

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MAX-PLANCK-INSTITUT  
FÜR PHYSIK



# Upgrade of the ATLAS experiment

## The High-Luminosity LHC (HL-LHC)

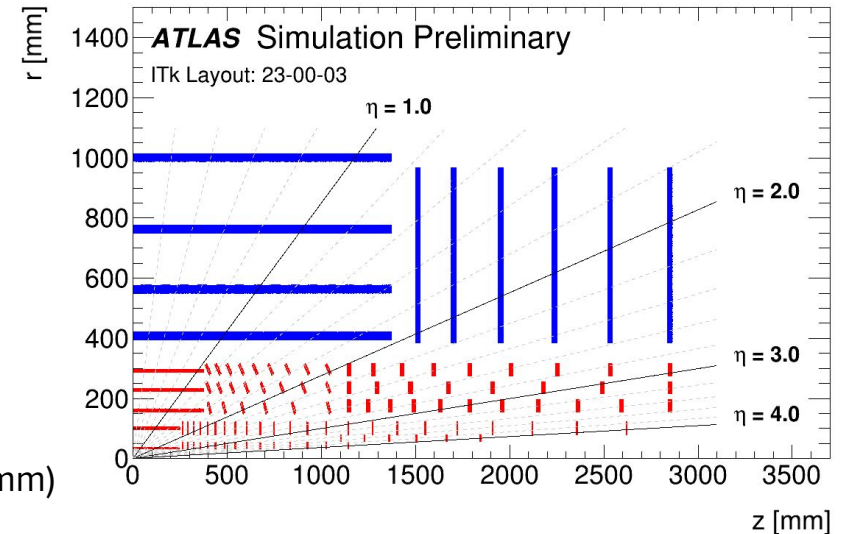
- data taking from [2030](#)
- challenging environment due to increased:
  - instantaneous luminosity ( $\sim 7.5 \cdot 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$ )
  - pile-up events per bunch crossing ( $\sim 200$  events/bunch crossing)
  - radiation damage (TID up to 10 MGy)
- upgrade of all detector systems of the ATLAS Experiment

The current Inner Detector will be replaced with the **Inner Tracker (ITk)** consisting of silicon **strip** and **pixel** modules.

## The ITk Pixel detector will include:

- single-chip 3D sensors in L0 ( $r = 34 \text{ mm}$ )
  - $2 \times 2 \text{ cm}^2$  size;
- four-chip (quad) planar sensors in L1-L4 ( $r = 99 - 291 \text{ mm}$ )
  - $4 \times 4 \text{ cm}^2$  size.

A schematic depiction of the ITk Layout

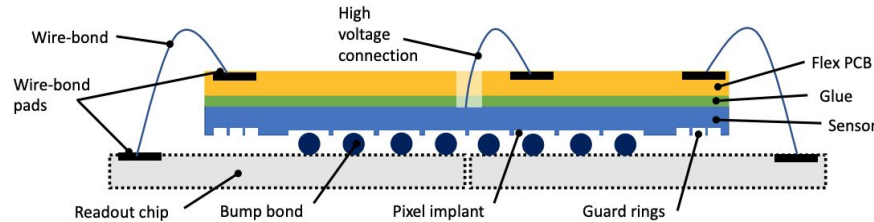


# ATLAS ITk pixel modules assembly and testing

The ITk pixel modules are assembled in two steps:

- **bump bonding**, where readout chips are attached to the sensor → bare module;
- **module assembly**, where the flex PCB (hybrid) is glued to the bare module

Beyer (2019)



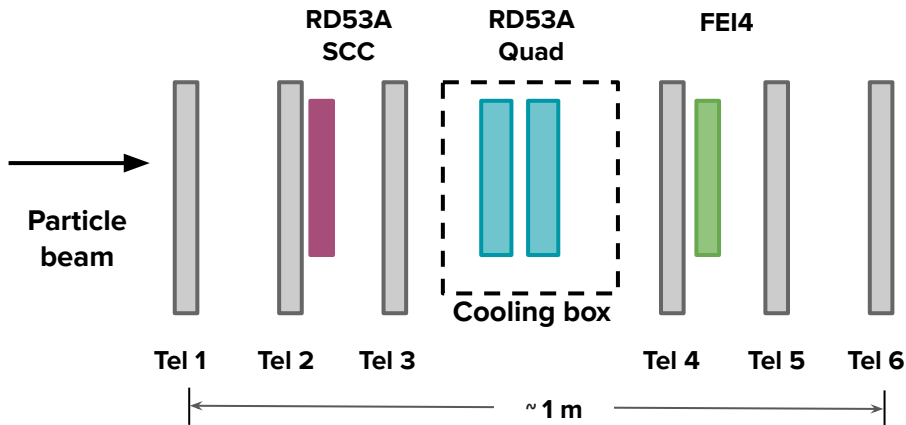
Module testing setup at MPP



The performance of assembled modules is evaluated in laboratory and **test-beam** measurements.

# Experimental setup

- The test-beam measurements are performed at CERN SPS in the North Area
  - Beam of pions with  $E = 120.0 \text{ GeV}$
- Scintillators in coincidence are used for triggering purposes
- [EUDAQ1](#) framework is used for the data acquisition



## Beam telescope

**RD53A single-chip card (SCC)** as a timing reference

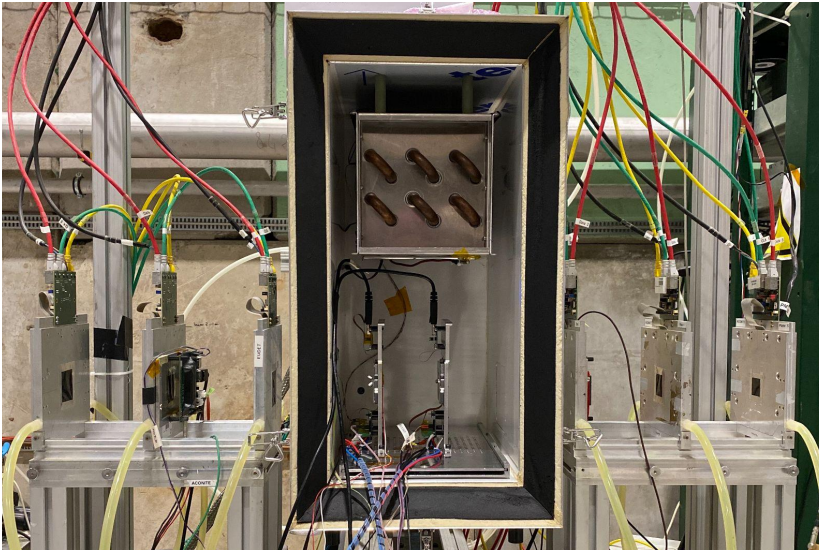
**FEI4 single-chip card**

**RD53A quad modules** with n-in-p planar sensors of 150  $\mu\text{m}$  thickness and 50x50  $\mu\text{m}^2$  pixel size:

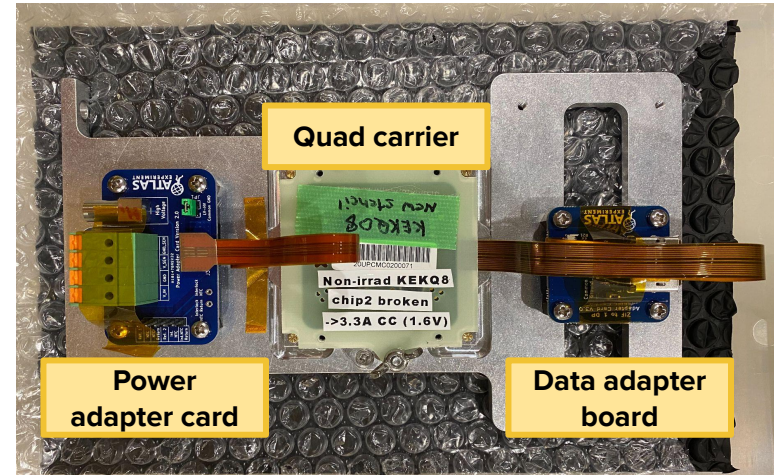
- non-irradiated Hamamatsu (HPK) Q8
- non-irradiated Micron Q2
  - PT biasing structure
- irradiated HPK Q4
  - Fluence:  $\phi_{\text{eq}} = 5 \times 10^{15} \text{ n}_{\text{eq}} \text{ cm}^{-2}$

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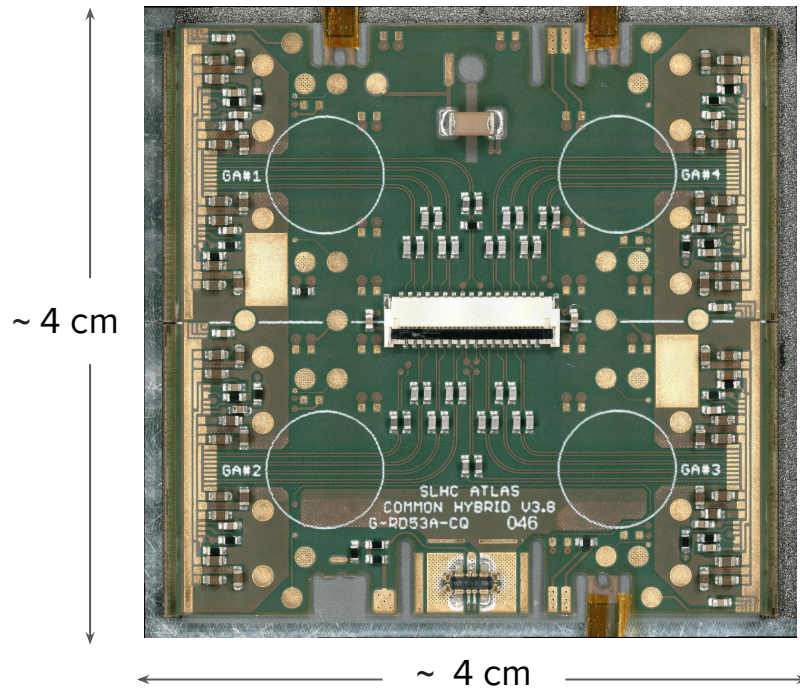
Frame with mounted RD53A quad module



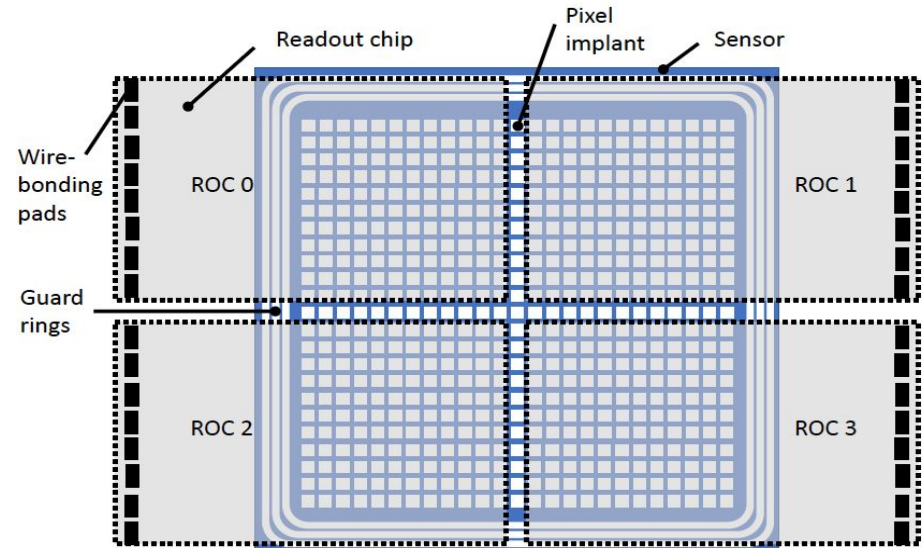
- To be able to scan different chips, the position of the module with respect to the beam is changed.

# ATLAS ITk RD53A quad modules

Example of the assembled RD53A module

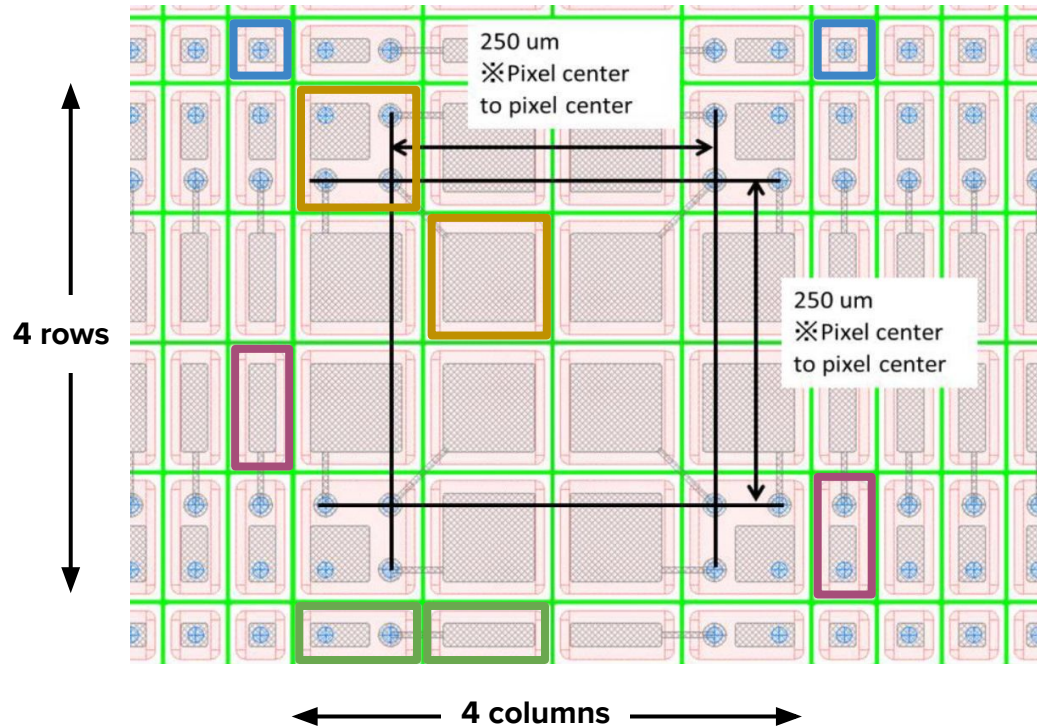


Sketch of quad-module layout



# Inter-chip region

- The gap between the four chips bump bonded to the quad sensor
  - Four central columns and rows of the sensor
  - Different pixel sizes to cover this area



**Pixel size** (column  $\times$  row; column=X, row=Y)

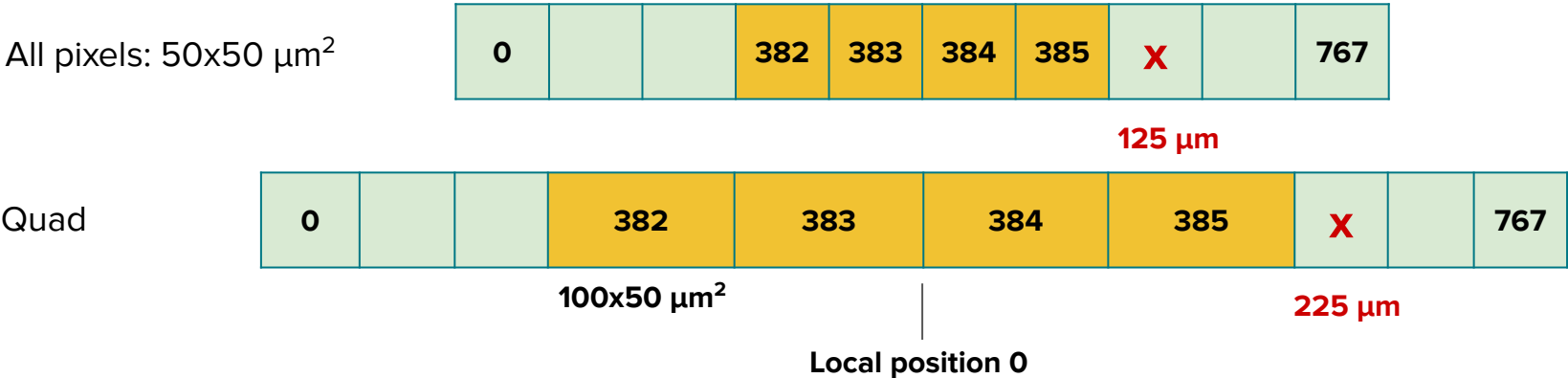
- $50 \times 50 \mu\text{m}^2$
- $100 \times 100 \mu\text{m}^2$
- $50 \times 100 \mu\text{m}^2$
- $100 \times 50 \mu\text{m}^2$

# Data reconstruction

- The raw data contain basic pixel hit information: column, row, ToT, LV1 ID
  - Hits close in space are grouped into clusters
  - Column and row of the cluster center can be converted to the hit position
- The [Corryvreckan](#) framework is used for the data reconstruction and analysis
  - In this framework the sensor is expected to have a uniform pixel matrix.

} In the data reconstruction and analysis software

**Example:** The hit cluster center has column ID: 386

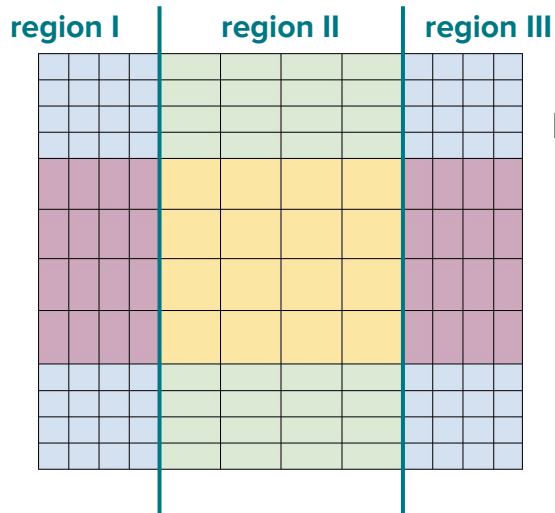


*Pixel number refers to the center of the pixel*



# New Corryvreckan geometry class

- The new - [ITkPixQuad](#) - class implemented
  - A detector with this inter-chip region configuration is created by specifying coordinates in the detector configuration file as: `coordinates = "cartesian_itkpixquad"`
  - The pixel size in each direction depends on the region on the quad



Following functions were modified according to the quad geometry:

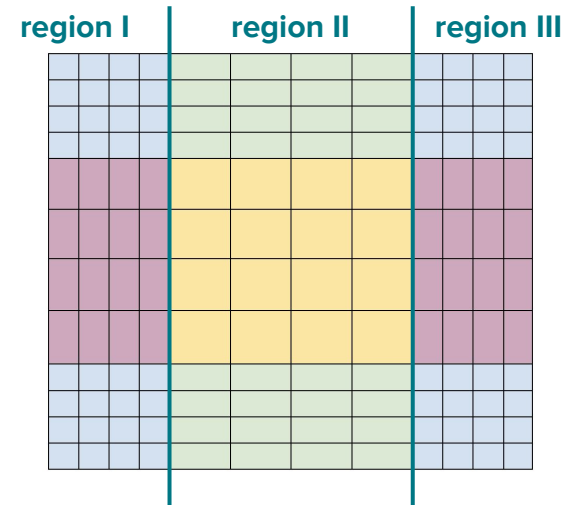
- Calculation of the local position based on the column and row;
- Determination of the row and column from the local position;
- Calculation of the size of the detector;
- Calculation of the in-pixel position from column/row and local position;
- Calculation of the spatial resolution based on the column/row of the pixel.

# New Corryvreckan analysis module

- **Previous experience:** test-beam analysis when testing only single-chip cards performed using AnalysisDUT and AnalysisEfficiency modules
  - Both modules would have to be modified to study the quad module and inter-chip region
- The new - **AnalysisITkPixQuad** - module created, which can be used to determine:
  - Cluster size distribution in X and Y;
  - Residual distribution in X and Y;
  - Hit efficiency.

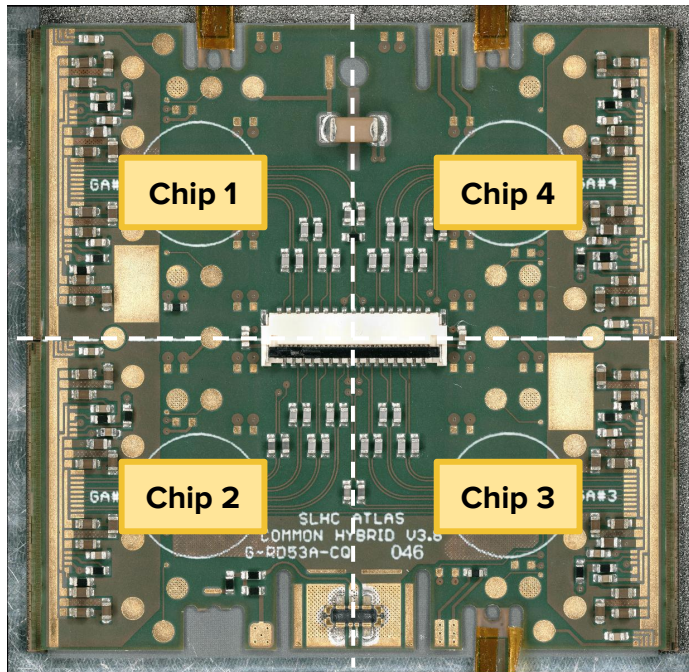
All quantities can be determined separately for:

- 50x50  $\mu\text{m}^2$  size pixels;
- the inter-chip region.



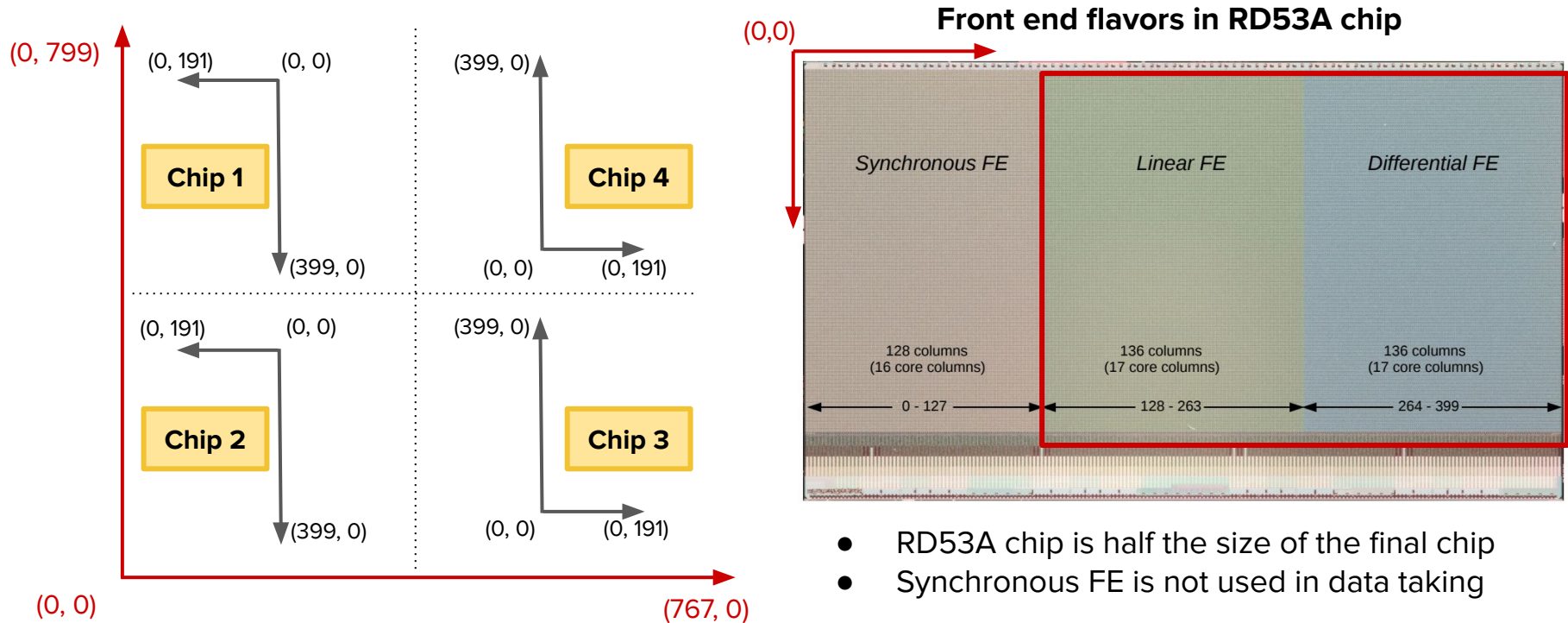
# RD53A Quad module layout

- Readout system: record hits per chip
- EUDAQ converter: combine data from four chips into one detector plane
- Corryvreckan framework: read data per detector plane



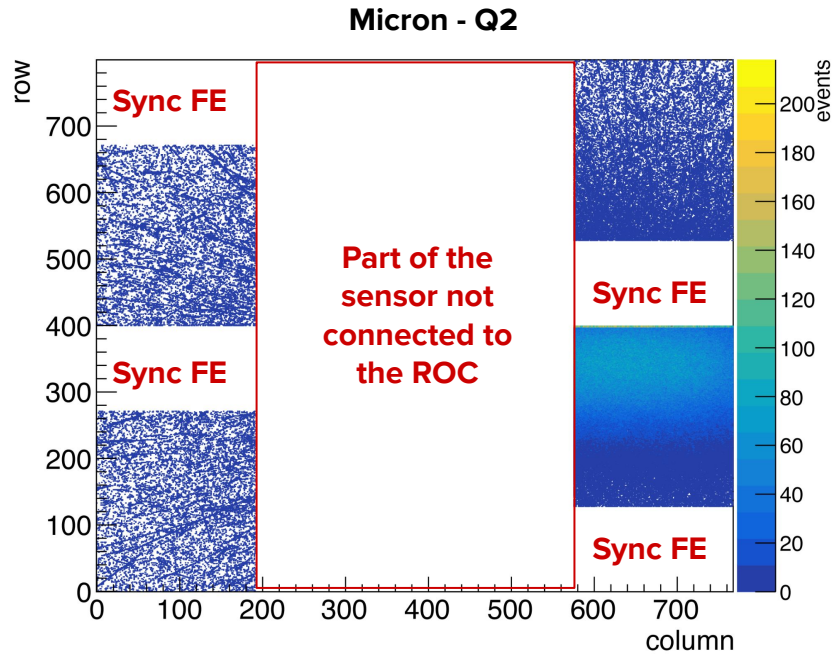
# RD53A Quad module layout

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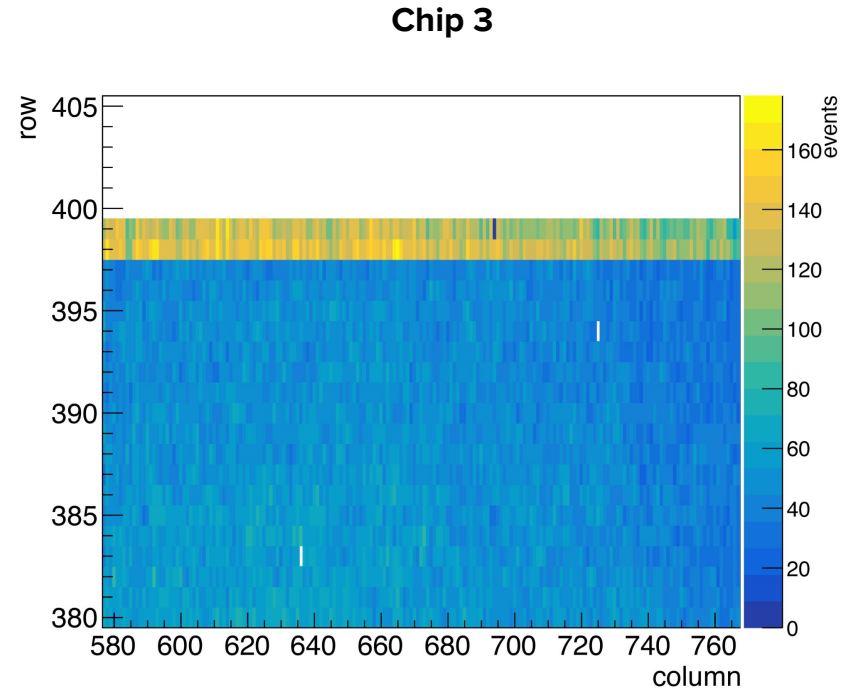


- RD53A chip is half the size of the final chip
- Synchronous FE is not used in data taking

# Hit map example



- Module positioned such that the beam is focused on chip 3



Row **398** and **399**:  $50 \times 100 \mu\text{m}^2$  pixels - twice as many hits compared to other pixels

# Hit efficiency measurement

- **Track selection**

- Only tracks with a hit on the reference DUT (timing reference) within LV1 limits are considered for the analysis

- **DUT cluster association**

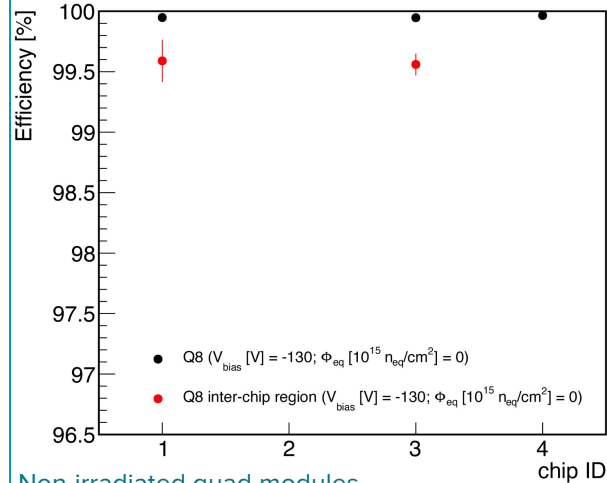
- Clusters on quad modules are assigned to the reconstructed tracks if they are within twice the pixel pitch in both directions

- **Hit efficiency**

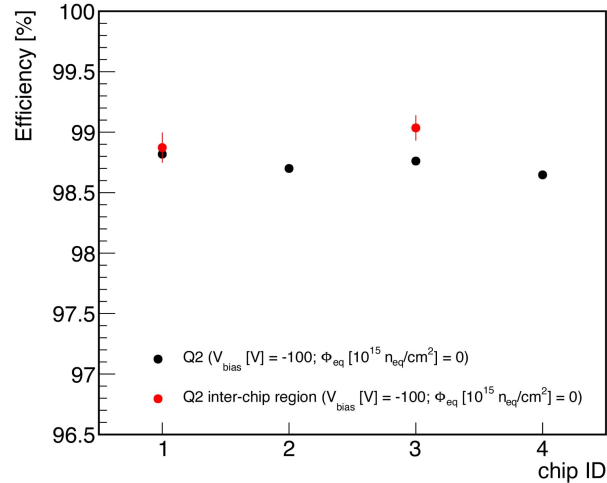
$$\varepsilon = \frac{\text{number of tracks with an assigned cluster on the DUT}}{\text{total number of tracks intersecting the DUT}}$$

# Hit efficiency per chip

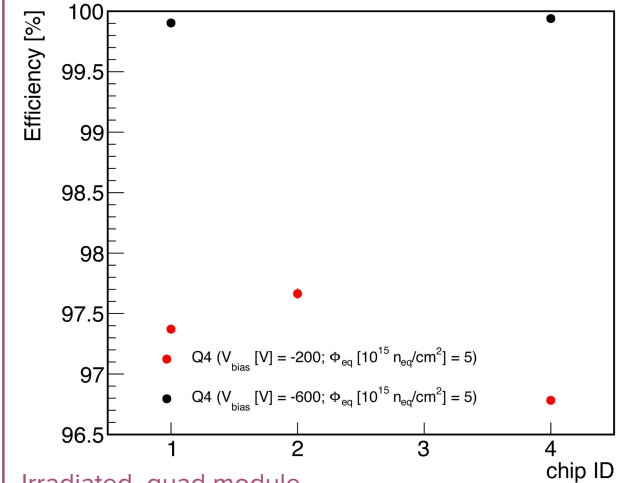
## HPK - Q8



## Micron - Q2



## HPK - Q4



Non-irradiated quad modules

Irradiated quad module

## HPK - Q8

- Chip 2 was disabled
- $\varepsilon > 99.9\%$  for all 3 measured chips
- $\varepsilon > 99.5\%$  (inter-chip region)

## Micron - Q2

- All chips enabled
- $\varepsilon > 98.5\%$

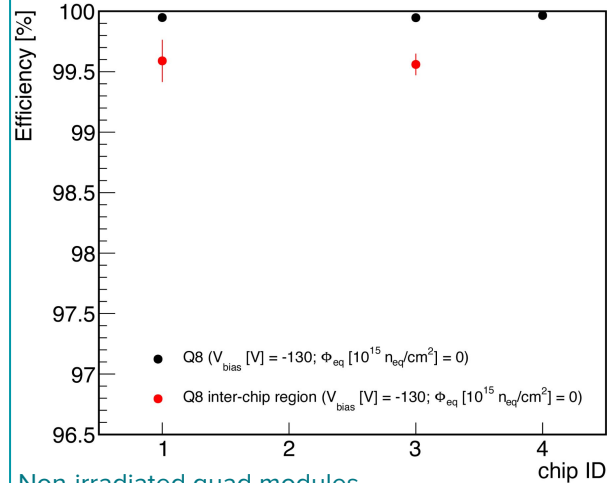
## HPK - Q4

- Chip 3 was disabled
- $\varepsilon \sim 97.0\%$  (-200 V)
- $\varepsilon \sim 99.9\%$  (-600 V)

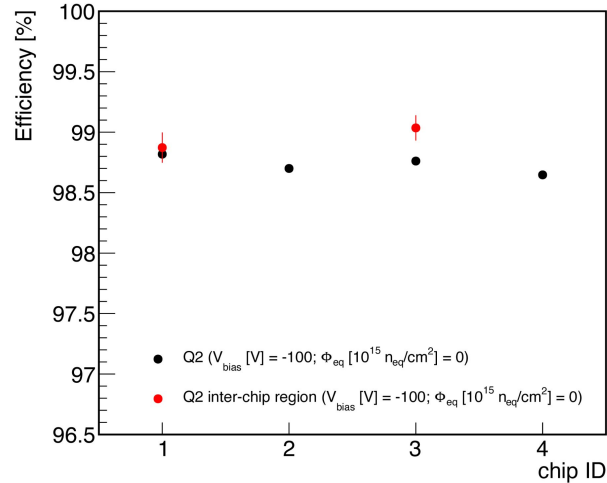
The efficiency uncertainties are statistical.

# Hit efficiency per chip

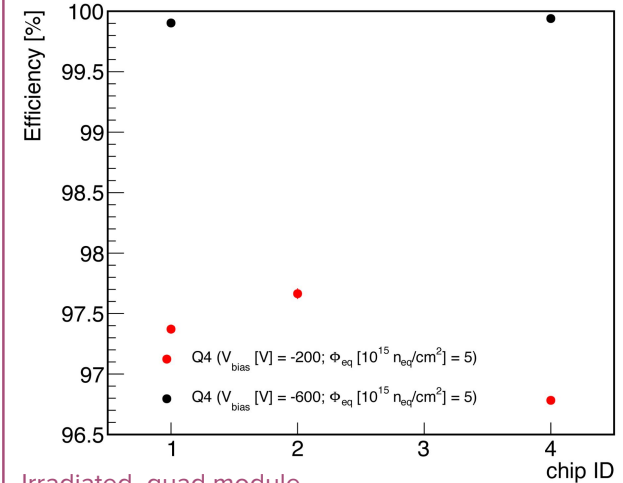
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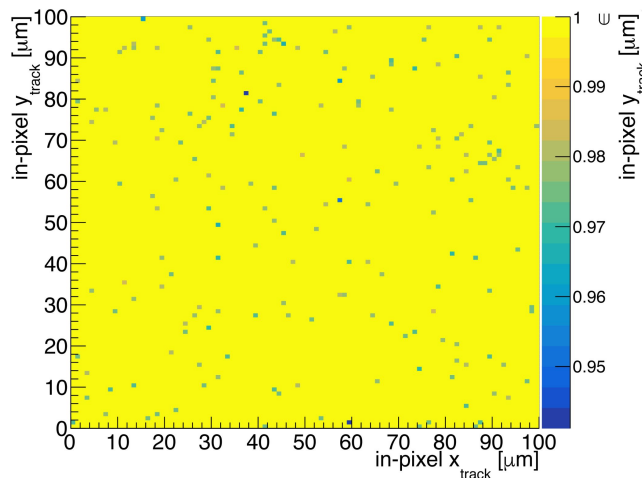
ITk requirements for planar sensors: Non-irradiated modules > 98%;

Irradiated modules > 97%

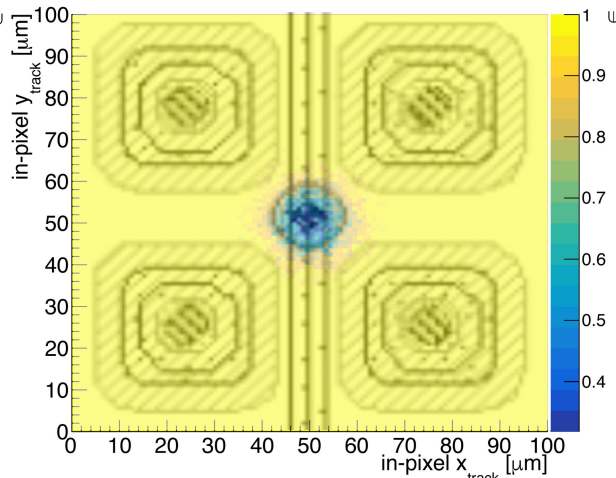


# Hit efficiency map (50x50 $\mu\text{m}^2$ pixels)

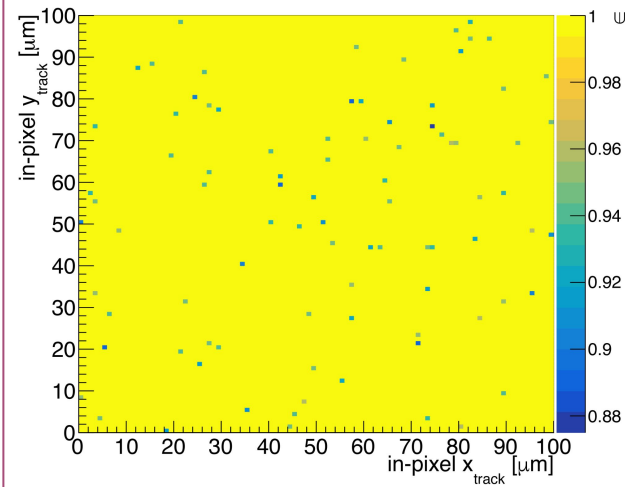
HPK - Q8



Micron - Q2



HPK - Q4



Non-irradiated quad modules

Irradiated quad module

Threshold tuning: 1500e  
Bias voltage: -130 V  
Leakage current: -0.2  $\mu\text{A}$   
T:  $\sim 20^\circ\text{C}$

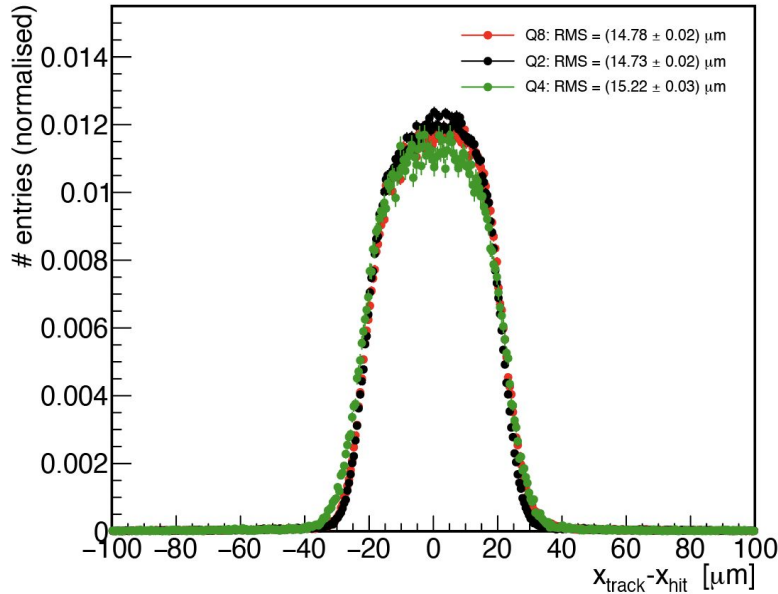
Threshold tuning: 1500e  
Bias voltage: -100 V  
Leakage current: -4.8  $\mu\text{A}$   
T:  $\sim 25^\circ\text{C}$

Threshold tuning: 1500e  
Bias voltage: -600 V  
Leakage current: -100  $\mu\text{A}$   
T:  $\sim -30^\circ$

with a punch-through biasing structure

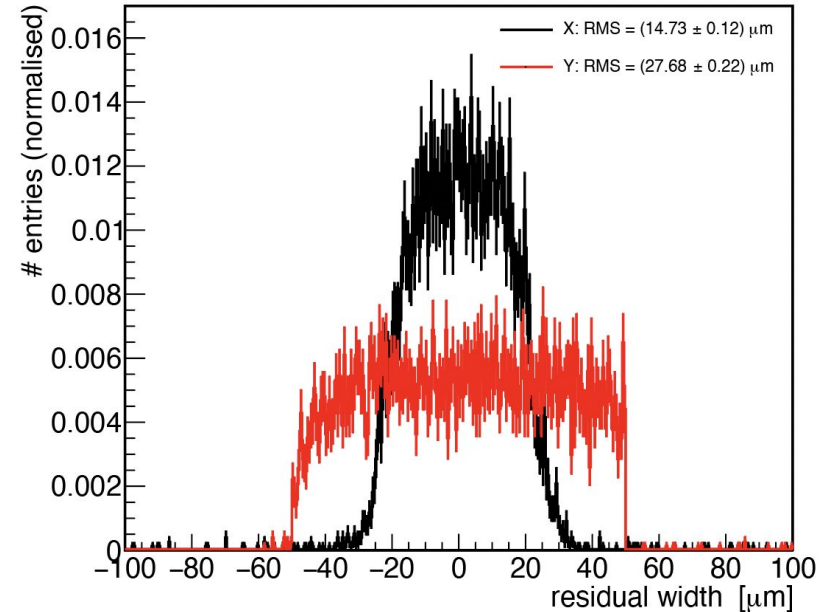
# Residual distribution

50x50  $\mu\text{m}^2$  pixels: X dimension



Unbiased residuals  $r^2 = \sigma_{\text{int}}^2 + \sigma_{\text{tel}}^2$

Q8: inter-chip region



$\sigma_{\text{int}}$  (50  $\mu\text{m}$ , 100  $\mu\text{m}$ ) = 14.43  $\mu\text{m}$ , 28.87  $\mu\text{m}$   
 $\sigma_{\text{tel}} \sim 5 \mu\text{m}$

# Summary and outlook

- Three RD53A quad modules have been successfully measured during the test-beam campaigns in 2021
  - Two non-irradiated quad modules;
  - One irradiated quad module.
- The data is reconstructed and analysed using the Corryvreckan framework
  - The framework was further developed to allow the analysis of sensors with non-uniform matrices.
- The hit efficiencies of the modules fulfill the requirements for ITk planar sensors
  - Non-irradiated modules > 98%;
  - Irradiated modules > 97%.
- The functionality of the inter-chip region is verified
- The residual distributions for three measured quads are compatible with the expectation for respective pixel sizes.
- More studies will be performed with ITkPix v1.1 modules.